Analog Power

AM2308NE

D

N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low r_{DS(on)} and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY V_{DS} (V) $r_{DS(on)} m(\Omega)$ $\mathbf{I}_{\mathbf{D}}(\mathbf{A})$ $60 @ V_{GS} = 4.5V$ 3.5 30 82 @ $V_{GS} = 2.5V$ 3.0



RoHS

COMPLIANT

HALOGEN

FREE

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology



| ESD Protected | | | | | |
|---|---|------------|-------------|-------|--|
| 2000V | | | | | |
| ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C U | NLESS OI | HERWIS | SE NOTED |) | |
| Parameter | | | Limit | Units | |
| Drain-Source Voltage | | | 30 | v | |
| Gate-Source Voltage | | | ± 12 | v | |
| | $T_A=25^{\circ}C$ | т_ | 3.5 | A | |
| Continuous Drain Current ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | I D | 2.8 | | |
| Pulsed Drain Current ^b | I _{DM} | 16 | | | |
| Continuous Source Current (Diode Conduction) ^a | | | 1.25 | Α | |
| | T _A =25°C | P_{D} | 1.25 | w | |
| Power Dissipation ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | гD | 0.8 | | |
| Operating Junction and Storage Temperature Range | | TJ, Tstg | -55 to 150 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | | | | |
|--|--------------|-----------------|---------|-------|--|--|--|--|
| Parameter | | Symbol | Maximum | Units | | | | |
| Maximum Junction-to-Ambient ^a | t <= 10 sec | D | 100 | °C/W | | | | |
| | Steady-State | $R_{\theta JA}$ | 166 | °C/W | | | | |

Notes

- Surface Mounted on 1" x 1" FR4 Board. a.
- b. Pulse width limited by maximum junction temperature

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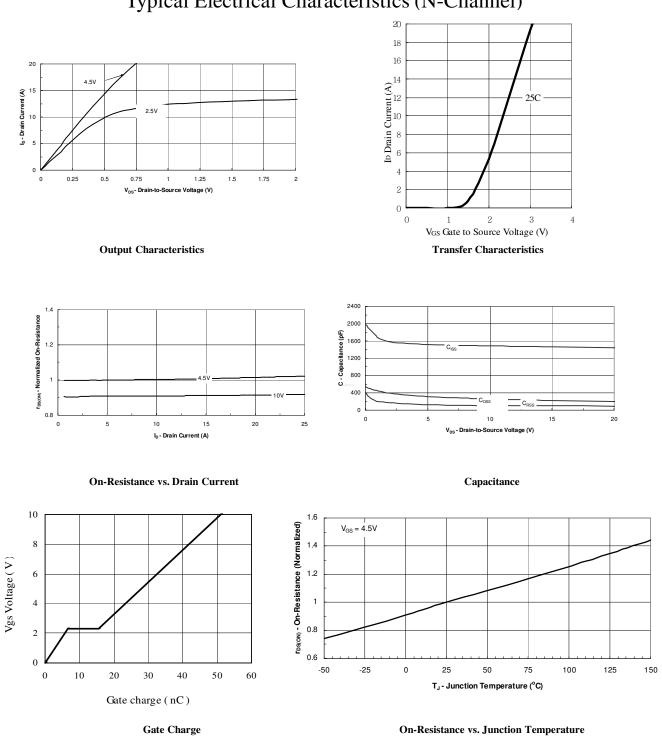
| SPECIFICATIONS ($T_{A} = 25^{\circ}$ C UNLESS OTHERWISE NOTED) | | | | | | | |
|---|---------------------|---|--------|-----|-----|--------|--|
| Parameter | Symbol | Test Conditions | Limits | | | Unit | |
| | | Test Conditions | Min | Тур | Max | Umt | |
| Static | | | | | | | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \text{ uA}$ | 0.6 | | | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = 12 V$ | | | ±10 | uA | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 1 | uA | |
| | | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{I} = 55^{\circ}\text{C}$ | | | 25 | uA | |
| On-State Drain Current ^A | I _{D(on)} | $V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$ | 6 | | | А | |
| Drain-Source On-Resistance ^A | r _{DS(on)} | $V_{GS} = 4.5 \text{ V}, I_D = 3.5 \text{ A}$ | | | 60 | mΩ | |
| | | $V_{GS} = 2.5 \text{ V}, I_D = 3 \text{ A}$ | | | 82 | 1115.2 | |
| Forward Tranconductance ^A | g _{fs} | $V_{DS} = 15 \text{ V}, I_{D} = 3.5 \text{ A}$ | | 6.9 | | S | |
| Diode Forward Voltage | V _{SD} | $I_{s} = 2.3 \text{ A}, V_{Gs} = 0 \text{ V}$ | | 0.8 | | V | |
| Dynamic ^b | | | | | | | |
| Total Gate Charge | Q _σ | $V_{DS} = 15 \text{ V}, V_{GS} = 2.5 \text{ V},$ $I_{D} = 3.5 \text{ A}$ | | 6.3 | | nC | |
| Gate-Source Charge | Q _{os} | | | 0.9 | | | |
| Gate-Drain Charge | Q _{ad} | ID = 3.5 A | | 1.9 | | | |
| Turn-On Delay Time | t _{d(on)} | | | 16 | | | |
| Rise Time | t _r | V_{DD} = 25 V, R_L = 25 Ω , $I^{\rm D}$ = 1 A, | | 5 | | nS | |
| Turn-Off Delay Time | t _{d(off)} | VGEN = 10 V | | 23 | | ns | |
| Fall-Time | t _f | | | 3 | | | |

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

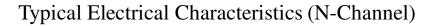
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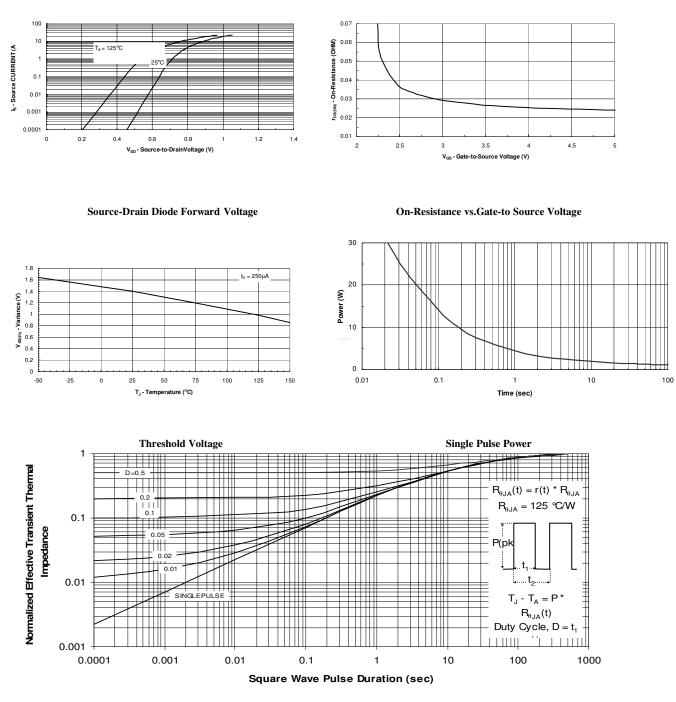
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Typical Electrical Characteristics (N-Channel)

 $^{\odot}$ PRELIMINARY





Normalized Thermal Transient Impedance, Junction-to-Ambient

Package Information

